

A Model of Charge-Transfer Excitons: Diffusion, Spin Dynamics, and Magnetic Field Effects

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Supporting Information

ABSTRACT: In this Letter, we explore how the microscopic dynamics of charge-transfer (CT) excitons are influenced by the presence of an external magnetic field in disordered molecular semiconductors. This influence is driven by the dynamic interplay between the spin and spatial degrees of freedom of the electron—hole pair. To account for this interplay, we have developed a numerical framework that combines a traditional model of quantum spin dynamics with a stochastic coarse-grained model of charge transport. This combination provides a general and efficient methodology for simulating the effects of magnetic field on CT state dynamics, therefore providing a basis for revealing the microscopic origin of experimentally observed magnetic field effects. We demonstrate that simulations carried out on our model are capable of reproducing experimental results as well as generating theoretical predictions related to the efficiency of organic electronic materials.



harge-transfer (CT) states play a fundamental role in mediating interconversion between bound electronic excitations and free charge carriers in organic electronic materials. For processes that require this interconversion, such as electroluminescence in organic light emitting diodes (OLEDs) and photocurrent generation in organic photovoltaics (OPVs), low-energy (thermalized) CT states are often implicated as a precursor to efficiency loss pathways.¹⁻¹² Despite this, much remains to be understood about the properties of CT states and how they contribute to various energy loss mechanisms. Due to their short lifetime and low optical activity, attempts to interrogate CT states directly have brought limited success. Notably, however, recent experiments that probe CT states indirectly via their response to an applied magnetic field have demonstrated the potential to reveal new information about this elusive class of excited states.¹³⁻²¹ Unfortunately, extracting this information is challenging because it is encoded by a complex interplay of electronic and nuclear spin dynamics.^{15,22,23} This interplay is further complicated when the dynamics of the electron-hole spin state (or the specific experimental observable) is coupled to a source of fluctuating microscopic disorder such as charge transport or molecular conformational dynamics.²¹ In this Letter, we focus on disentangling this interplay.

The dependence of an experimental observable on an applied magnetic field is generically referred to as the magnetic field effect (MFE). For CT-mediated processes, MFEs require that the observed physical property depends either directly or indirectly on the spin state of the electron-hole pair. For instance, spin selection rules for radiative electron-hole recombination can give rise to a magnetic field-dependent electroluminescence yield.^{20,24–26} To understand specifically how CT state properties are influenced by the presence of a

magnetic field, it is natural to describe the spin state of the electron-hole pair in a standard basis of singlet and triplet states. If the electron and hole positions are static, then MFEs emerge when the Zeeman splitting of the triplet energy levels becomes comparable to or larger than interactions that govern population transfer between the three triplet spin states (i.e., T_{-} , T_{0} , and T_{+}).^{21,22} Under typical experimental conditions (i.e., applied field strengths ~ 1 T), the magnitude of the Zeeman splitting is much smaller than the thermal energy (i.e., $\Delta E_{Zeeman} \ll k_{\rm B}T$), and thus, it has negligible effect on equilibrium properties. The net result, as illustrated in Figure 1a, is that the time scale for spin-mixing dynamics is slowed in the presence of a magnetic field.

The microscopic origin of MFEs becomes more complicated if the electron and hole positions are dynamic. This is because variations in electron-hole separation can drive fluctuations in the value of the exchange coupling that determines the energy difference between the singlet and triplet states. This coupling can be large compared to thermal energies but decays exponentially with electron-hole separation. Even subtle changes in CT state configuration can result in significant variations in the equilibrium singlet-triplet ratio. The ability of the CT spin state to respond to these time-dependent variations is mediated by the time scale for spin-mixing dynamics, which, as described above, can be tuned by the application of an external magnetic field. It is this competition of time scales, between spin and spatial dynamics, that ultimately determines the magnitude of the observed MFEs. Perhaps more importantly though is that the MFEs encode

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Figure 1. (a) Relative energy of the three, otherwise degenerate, triplet levels split (Zeeman splitting) by a magnetic field. Consequently, as indicated with red arrows, the time scale for spin-mixing dynamics can be varied with an external magnetic field. (b) Schematic depiction of the model system in which donor and acceptor molecules (represented as blue- and red-shaded circles, respectively) reside on opposite halves of an ordered lattice. The electron (-) and hole (+) occupy individual molecules whose orbital energies vary as indicated by shading. The relative energy of singlet and triplet states is determined by the exchange splitting, which decays rapidly with electron—hole separation. When the electron and hole occupy neighboring sites (top), this exchange splitting is typically larger than thermal energies. When the electron and hole are separated by one or more molecules (bottom), the exchange splitting is negligible, resulting in degenerate singlet and triplet energy levels.

information that can be used to characterize the microscopic dynamics of the electron-hole pair.

In this Letter, we address the challenge of predicting and interpreting the results of magnetic-field-sensitive experiments by utilizing numerical simulation. We present a model for CT state dynamics that incorporates magnetic-field-dependent spin dynamics into an efficient coarse-grained description of electron-hole transport. The inclusion of spin dynamics represents an extension of the model that was previously used to simulate transient photoluminescence data in ref 19. We demonstrate that this extended model is capable of reproducing experimental results and revealing fundamental aspects of CT state dynamics that are otherwise inaccessible to current experimental techniques. First, however, we describe the general theoretical framework that underlies our model for simulating CT state dynamics in disordered molecular systems.

In our model, a CT state is described as an oppositely charged pair of spin-1/2 particles (i.e., an electron and hole), each localized on separate molecules. We utilize a coarsegrained description of a molecular semiconductor in which individual molecules are represented as discrete sites. Each molecular site is characterized by a position, \vec{r}_{ij} HOMO energy, $E_i^{(\text{HOMO})}$, LUMO energy, $E_i^{(\text{LUMO})}$, and hyperfine magnetic field, $\vec{B}_i^{(\text{hf})}$, which arises from the interaction of the electronic magnetic moment with the nuclear magnetic moment. CT state properties are determined by combining these parameters, for the electron- and hole-occupied sites, with a description of the electron- hole spin state, which we represent in terms of a two-spin quantum density matrix, ρ . The energy of a CT state configuration in which the electron occupies site i and the hole occupies site j is given by

$$E_{ij}^{(CT)}(\rho) = E_{ij}^{(E)} + E_{ij}^{(S)}(\rho)$$
(1)

where $E_{ij}^{(E)}$ is the electronic energy and $E_{ij}^{(S)}(\rho)$ is the spin energy. The electronic energy, which depends on the spatial configuration of the electron-hole pair, is given by

$$E_{ij}^{(E)} = E_{i}^{(LUMO)} - E_{j}^{(HOMO)} - \frac{e^{2}}{4\pi\epsilon|\vec{r_{i}} - \vec{r_{j}}|}$$
(2)

where *e* is the elementary unit of charge and ϵ is the dielectric constant. In this expression, the first two terms represent the vertical excitation energy (i.e., the HOMO–LUMO gap) of the given CT state, and the final term describes the electrostatic

electron-hole attraction.²⁷ The spin energy is given by $E_{ij}^{(S)} = \text{Tr}[H_{ij}^{(S)} \rho]$, where $H_{ij}^{(S)}$ is the spin Hamiltonian

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$$H_{ij}^{(S)} = g\mu_{b} [(\vec{S}_{e} + \vec{S}_{h}) \cdot \vec{B}^{(app)} + \vec{S}_{e} \cdot \vec{B}_{i}^{(hf)} + \vec{S}_{h} \cdot \vec{B}_{j}^{(hf)}] - J(|\vec{r}_{i} - \vec{r}_{j}|) \vec{S}_{e} \cdot \vec{S}_{h}$$
(3)

where μ_b is the Bohr magneton and g is the g-factor for the magnetic moment; \vec{S}_e and \vec{S}_h are the spin operators for the electron and hole, respectively. The terms in the square brackets describe the interaction of the electron and hole spins with the applied magnetic field and the local hyperfine field, denoted as $\vec{B}^{(\text{app})}$ and $\vec{B}_i^{(\text{hf})}$, respectively. To model the hyperfine interaction with the nuclear spins, we adopt the semiclassical approach of Schulten and Wolynes, in which hyperfine interactions are approximated to be static and site-dependent, with $\vec{B}_i^{(\text{hf})}$ drawn randomly from the three-dimensional Gaussian distribution.^{28,29} The final term in eq 3 describes the exchange interaction between the electron and hole spins, where J(r) is the exchange coupling, which depends on the electron-hole separation, $r = |\vec{r}_i - \vec{r}_i|$.

The time evolution of our model is separated into a spatial part, which describes the dynamics of electron and hole positions, and a spin part, which describes the time evolution of the CT spin density matrix. The dynamics of electron and hole positions are determined by a kinetic Monte Carlo (KMC) algorithm,³⁰ whereby the electron and hole migrate via stochastic hops between neighboring molecular sites. We restrict the dynamics to include only single-particle hops (i.e., electron or hole) and assign hopping rates following the Miller–Abrahams formula.³¹ As such, the rate for an electron to hop from site i to site i' while the hole is fixed at site j is given by

$$k_{ij \to i'j} = \nu_0 \exp\left[-\frac{(\Delta E_{ij \to i'j} + |\Delta E_{ij \to i'j}|)}{2k_{\rm B}T}\right]$$
(4)

where ν_0 is the normalized hopping frequency, $k_{\rm B}T$ is the Boltzmann constant times temperature, and $\Delta E_{ij \to i'j} = E_{i'j}^{\rm (CT)} - E_{ij}^{\rm (CT)}$. The hole hopping rate $k_{ij \to ij'}$ is given by an analogous formula.

The spin dynamics are modeled with an open quantum systems approach in which the electron-hole spin state, $\rho(t)$, is coupled to a bath of harmonic oscillators and propagated via a secular Redfield equation.³² The spin Hamiltonian in eq 3

depends on CT state configuration, and therefore, the stochastic spatial dynamics of the electron—hole pair imparts a time dependence to the spin Hamiltonian. In between charge hopping events, however, the electron and hole positions are assumed to be fixed, and thus, the Hamiltonian of eq 3 is static. A detailed description of the spin dynamics and the Redfield formalism can be found in the Supporting Information.

The empirical model parameters that define the coarsegrained system can be assigned in a variety of ways. For instance, they can be inferred through the analysis of experimental data or computed via ab initio molecular simulation. The ability to vary these parameters in order to describe different materials provides the versatility to adapt this model to describe the broad range of systems that exhibit MFEs. We now demonstrate this versatility by applying our model to investigate a recent set of magnetic-field-dependent experiments aimed at probing CT state dynamics.

Recently, Adachi et al.³³ and Baldo et al.^{18,19} have developed a donor-acceptor pair of organic dye molecules, 4,4',4"-tris[3methylphenyl(phenyl)amino]-triphenylamine (m-MTDATA) and tris-[3-(3-pyridyl)-mesityl]borane (3TPYMB), which can support electronically excited CT states that can undergo direct singlet radiative recombination. For thin film blends of these molecules, this radiative process is evident in the photoluminescence (PL), which exhibits a long time ($\sim 30 \ \mu s$) decay that has been attributed to reverse intersystem crossing from a long-lived population of CT triplets. Focusing on this long time PL signature, time-resolved fluorescence microscopy has revealed that the PL profile undergoes both a transient spatial broadening and a transient red shift,¹⁹ indicating that CT states are mobile along the donor-acceptor interface and sensitive to the presence of static energetic disorder. The PL also exhibits pronounced MFEs, indicating that CT state dynamics may involve fluctuations in electron-hole separation. These observations led the authors to hypothesize that CT dynamics proceed through the asynchronous motion of localized electrons and holes.¹⁹ Here, we apply our model to this system in order to (i) confirm that the hypothesized description of CT state dynamics is consistent with the observed MFEs and (ii) elaborate on the role of spin dynamics in charge-transfermediated processes such as photocurrent generation and photoluminescence.

To adapt our model to this system, we utilized a parametrization that was based only on experimentally available data. The model system included a regular lattice of molecular sites where the lattice spacing was based on the average excluded volume size of the constituent molecules. As illustrated in Figure 1b, the system was divided so that onehalf of the system contained only donor molecules and the other half contained only acceptor molecules. We assumed the presence of uncorrelated static energetic disorder, which was represented by assigning values of $E_i^{(\text{LUMO})}$ and $E_i^{(\text{HOMO})}$ randomly from a Gaussian distribution with standard deviation inferred from spectroscopy. Experimental data were also used to parametrize the exchange coupling, radiative recombination rate, and details of spin dynamics. A more detailed description of parameter values and how they were derived from experimental data is presented in the Supporting Information. The results presented in this Letter were generated using a twodimensional donor-acceptor system, such as illustrated in Figure 1. We also explored three-dimensional systems and found results to be similar in both two and three dimensions. The biggest qualitative difference between these two cases

appears in the early time relaxation (i.e., the first 5 μ s), where transient spatial broadening of the PL data (and the associated transient red shift) exhibits more rapid change in the threedimensional system (see Supporting Information Figure 2). This initial relaxation is particularly sensitive to the number of nearest neighbors (i.e., the coordination number) within the lattice. By comparing simulation data from both two-dimensional and three-dimensional systems, we find that the two-dimensional systems actually result in better quantitative agreement with experiment. This perhaps suggests that the three-dimensional interfacial morphology of the experimental materials features coordination numbers that are more similar to that of our two-dimensional model system.

To simulate CT state PL, we generated trajectories that were initiated in a pure singlet state with the electron and hole on adjacent sites at the donor-acceptor interface. We generated statistics by sampling many trajectories across many realizations of the static disorder. Individual trajectories were carried out for a finite observation time (τ_{obs} = 30 μ s), which was chosen to be approximately the experimental time window in ref 19; however, trajectories could also be terminated at earlier times via a radiative recombination event. We modeled radiative recombination as a spin-state-dependent stochastic event with a rate that was proportional to the singlet population and was only allowed if the electron and hole occupied adjacent interfacial sites (see the Supporting Information for more details).

We simulated transient PL by analyzing the energies and positions of the ensemble of CT states that underwent radiative recombination. We found that our model is capable of reproducing the experimentally obtained transient PL data (i.e., spatial broadening and red shift) with near-perfect agreement. A direct comparison of our simulation data to these experimental results can be found in the Supporting Information. Here, we narrow our discussion to focus on the unique capability of this model to reveal the effect of applied magnetic field on CT state dynamics.

In the results presented in ref 19, MFEs were quantified in terms of the field dependence of the integrated PL and photocurrent. We compute integrated PL by first generating an ensemble of trajectories at a given value of $B = |\vec{B}^{(app)}|$ and then evaluating the fraction of trajectories that terminate due to radiative recombination. Similarly, we relate integrated photocurrent to internal quantum efficiency (IQE), which is evaluated by computing the fraction of trajectories for which the electron-hole separation at $t = \tau_{obs}$ exceeds the Coulomb radius (i.e., the distance at which the electrostatic electronhole interaction is equal to the thermal energy, $k_{\rm B}T$). Because our model does not include nonradiative loss mechanisms, we expect our simulated values to be overestimated relative to experiment. We have accounted for these unknown loss mechanisms by scaling our results by a field-independent constant (we use scaling factors of 0.33 and 0.12 for photoluminescence and photocurrent, respectively).

Figure 2 contains a plot of the percent change in integrated PL and photocurrent as measured experimentally (solid lines) and as predicted from our simulation data (open circles). Experiments yield an increase in PL with the application of a magnetic field that saturates at fields approaching 0.5 T. There is a corresponding decrease in the integrated photocurrent (more fluorescing CT states leaves fewer free charge carriers for photocurrent generation). The simulated CT dynamics accurately reproduce the shape of the experimentally measured



Figure 2. Magnetic field dependence of the PL and photocurrent as determined experimentally (solid lines) and simulated with our model (open circles). The quantity plotted against the *y*-axis is the percentage change, measured relative to the case where B = 0. Filled circles correspond to simulated results in the absence of system—bath coupling for spin dynamics. The experimental data in this figure were originally reported in ref 19.

MFEs in both the integrated PL and the photocurrent. The ability of our model to reproduce both the experimentally obtained transient PL and MFEs indicates that our theoretical framework accurately captures the basic physics associated with CT state dynamics in this system. Building on this validation, we now turn our attention to the ability of this model to reveal information about CT dynamics that are experimentally unavailable. To begin, we consider the physical origins of singlet-triplet population transfer. For CT states in systems composed of light molecules (e.g., in the absence of spin-orbit coupling), it is often assumed that this intersystem crossing is driven only by the hyperfine coupling.^{16,17,28,34,35} However, our simulation results reveal that there are alternative spin relaxation pathways that play a significant role in facilitating spin-mixing dynamics. These spin relaxation pathways are described implicitly in our model in terms of a system-bath coupling in the Redfield relaxation tensor. This coupling drives the so-called "phase-shift" transition, mediating population transfer specifically between the singlet and the T₀ triplet state.²² If we silence this coupling, then the relatively weak hyperfine field $(\sim 1 \text{ mT})^{36,37}$ is easily overcome by an externally applied field, leading to MFEs that saturate at very small fields. This is illustrated (filled circles) in Figure 2, where the absence of this system-bath coupling results in MFEs that rise sharply and saturate at around B = 10-20 mT, in qualitative disagreement with experimental observations.

Using our model, we can explore the microscopic fluctuations that give rise to MFEs. To illustrate this, we consider two representative trajectories each generated at different values of B but exhibiting similar spatial dynamics. As illustrated in Figure 3a, the trajectories include three distinct segments: First, in segment A, the electron-hole pair is initiated as a singlet state on neighboring sites along the interface. Next, in segment B, the electron hops away from the interface to form an unbound CT state with a concomitant reduction in the exchange coupling. Finally, in segment C, the electron and hole reunite on neighboring interfacial sites prior to undergoing radiative recombination. Although the spatial dynamics of these two trajectories are similar, due to the differing applied magnetic field, their spin dynamics differ significantly. In order to appreciate these differences, we consider each trajectory separately, starting with the B = 0 case (green line in Figure 3a).



Figure 3. (a) Time-dependence of the singlet population for two typical trajectories, selected to exhibit similar spatial dynamics, carried out under different values of $B = |\vec{B}^{app}|$. The inset illustrates the hopping behavior of these trajectories, each of which ends abruptly with a radiative recombination event. (b) The distribution of the values of singlet population, $\rho_{\rm S}$, at the recombination time for trajectories generated at different values of applied magnetic field. The red and green dashed vertical lines represent the equilibrium values for the bound ($\langle \rho_{\rm S} \rangle = 0.05$) and unbound ($\langle \rho_{\rm S} \rangle = 0.25$) CT states, respectively. The blue dashed line represents the value of $\rho_{\rm S}$ for the bound CT state in two-state quasi-equilibrium.

The trajectory is initialized as a bound CT state with an interfacial exchange splitting of 50 meV that lowers the triplet state energy relative to that of the singlet state. This energy difference favors the formation of triplet states, with a Boltzmann-weighted singlet density of $\langle \rho_{\rm S} \rangle \approx 0.05$. The evolution of the spin state from the initial singlet state is mediated primarily by the system-bath coupling, with a characteristic relaxation time scale of approximately 40 ns. Before the spin state can fully relax, however, the system enters segment B by hopping into an unbound CT state configuration. In our model, any unbound state is free of exchange coupling, and thus, the singlet and triplet states are degenerate. The associated equilibrium singlet density for the unbound state is $\langle \rho_{\rm S} \rangle = 0.25$. The spin relaxation for this degenerate unbound state is ultrafast, as is evident in the rapid equilibration of the singlet population in Figure 3a. In segment C, the CT state reenters the bound state and proceeds again toward the bound singlet density of $\langle \rho_{\rm S} \rangle \approx 0.05$. During this equilibration, the CT state undergoes a radiative recombination event, signaling the termination of the trajectory.

For the trajectory generated with B = 0.1 T (black line in Figure 3a), the effect of CT configuration on the equilibrium $\langle \rho_{\rm S} \rangle$ is identical. The ability of the spin state to respond to changes in configuration, however, is significantly affected by the presence of the applied magnetic field. At B = 0.1 T, the intratriplet relaxation occurs on time scales much longer than

the length of the trajectory. Due to this separation in time scales, the spin dynamics of this trajectory can be understood in terms of a quasi-equilibrium between the S and T_0 states. Under this two-state quasi-equilibrium, the bound state singlet population approaches $\rho_S = 0.13$, and the unbound state approaches $\rho_S = 0.5$. The field-induced slowing of intratriplet spin relaxation therefore has the effect of both prolonging the redistribution of the initial singlet population and, perhaps more importantly, of amplifying the effect of fluctuations in electron-hole separation on the transient singlet population.

The qualitative insight generated by analyzing individual trajectories can be further supported through the statistical analysis of many trajectories. Figure 3b contains histograms that reveal the distribution of singlet density, ρ_{s} , among the population of fluorescing CT states. Each of the four histograms depicted in Figure 3b was generated under different values of *B*. For the case of B = 0, the distribution is peaked at around $\rho_{\rm S}$ = 0.05 (red dashed line), corresponding to the equilibrium $\langle \rho_{\rm S} \rangle$ for the bound CT state. The distribution also includes a tail that extends to $\rho_{\rm S}$ = 0.25 (green dashed line), reflecting the population of CT states that fluoresce shortly after re-entering the bound state, before fully equilibrating. This shows that even in the absence of an applied magnetic field, a significant portion of luminescent CT excitons exhibit nonequilibrium spin statistics that result directly from fluctuations in electron-hole separation. As B increases, the shape of the histograms changes to reflect two-state (S and T_0) quasiequilibrium, with peak at $\rho_{\rm S}$ = 0.13 (blue dashed line), that results from field-induced slowing of spin-mixing dynamics. The field dependence of these histograms highlights the microscopic origin of observed MFEs, namely, that fieldinduced nonequilibrium spin statistics serve to enhance the singlet population and thereby the PL yields.

The analysis described above clearly demonstrates the importance of the time-dependent exchange splitting on the spin dynamics. With our model, we can evaluate the role of this interfacial exchange splitting, J_0 , on predicted device performance. To do this, we have carried out a series of simulations each with varying values of J_0 . Our findings, shown in Figure 4,



Figure 4. Dependence of photovoltaic IQE on the magnitude of the interfacial exchange splitting as predicted from simulations carried out on our model system.

illustrate that larger J_0 is beneficial for OPV performance. Specifically, as J_0 increases from 0 to 80 meV, the simulated IQE increases by nearly 70%. Qualitatively, this efficiency increase arises because energetically favorable triplet states are spin-protected from radiative recombination, and thus, the electron and hole have more time to diffuse away from each other to generate free charges. By initiating CT states as spin-equilibrated free charges at the simulation boundary, our model can be utilized to simulate electroluminescence. Increasing exchange coupling was found to reduce electroluminescence efficiency, which is consistent with experimental observations reported in ref 38.

The model presented here offers an efficient and versatile tool that can be used to relate difficult to interpret magneticfield-sensitive experiments to the microscopic fluctuations of excited electron—hole pairs. By applying this model to the donor—acceptor blend described in ref 19, we have highlighted how MFEs emerge from the details of spin-mixing dynamics. Furthermore, we have illustrated how the interplay between spin and spatial dynamics contributes to CT state dynamics and experimentally observed MFEs. The insight that we have drawn highlights the benefit of simple models in guiding our intuition around complex physical systems. This model can be applied in a straightforward manner to describe the optoelectronic properties of other CT-mediated processes, perhaps those that involve more complicated interfacial molecular morphology.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.jpclett.6b00871.

Details of the spatial dependence of exchange splitting and radiative recombination, details of the Redfield formalism, comparison between model results, and transient photoluminescence data (PDF)

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Notes

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